Bidirectional high-side power switch for charger and USB-OTG combined applications

Rev. 1 — 11 September 2013

**Product data sheet** 

## 1. General description

The NX5P3001 is an advanced bidirectional power switch and ESD-protection device for combined USB-OTG and charger port applications. It includes undervoltage lockout, overvoltage lockout and overtemperature protection circuits designed to automatically isolate the power switch terminals when a fault condition occurs.

The device features two power switch input/output terminals (VBUSI and VBUSO), an open-drain acknowledge output (ACK), an enable input which includes logic level translation ( $\overline{EN}$ ) and low capacitance Transient Voltage Suppression (TVS) type ESD-clamps for USB data and ID pins.

When EN is set HIGH the device enters a low-power mode, disabling all protection circuits. When used in combined charger and USB-OTG applications the 30 V tolerant VBUSI switch terminal is used as the supply and switch input when charging, for USB-OTG the VBUSO switch terminal is used as the supply and switch input.

Designed for operation from 3.2 V to 6.35 V, it is used in battery charging and power domain isolation applications to reduce power dissipation and extend battery life.

### 2. Features and benefits

- 30 V tolerant VBUSI supply pin
- Wide supply voltage range from 3.2 V to 6.35 V
- Automatic switch operation for charging within the supply range
- I<sub>SW</sub> maximum 3 A continuous current
- Low ON resistance: 62 mΩ (typical) at a supply voltage of 5.0 V
- 1.8 V control logic input to open the switch
- Soft start turn-on slew rate
- Protection circuitry
  - Overtemperature protection
  - Overvoltage lockout
  - Undervoltage lockout
- ESD protection:
  - HBM ANSI/ESDA/JEDEC JS-001 Class 2 exceeds 2 kV
  - CDM AEC standard Q100-01 (JESD22-C101E)
  - ◆ IEC61000-4-2 contact discharge exceeds 8 kV for pins VBUSI, D-, D+ and ID
- Specified from –40 °C to +85 °C



### Bidirectional power switch for charger and USB-OTG combinations

## 3. Applications

- Smart and feature phones
- Tablets, eBooks

## 4. Ordering information

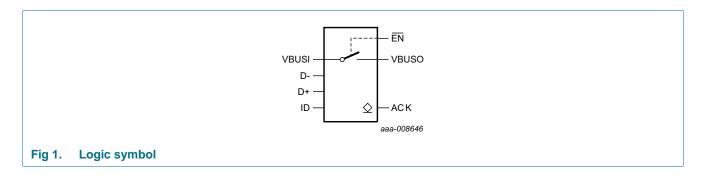
### Table 1.Ordering information

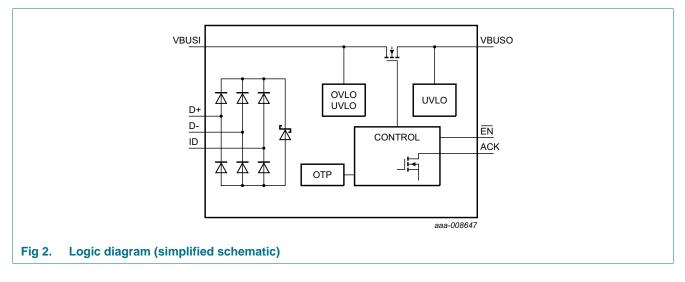
Type number	Package			
	Temperature range	Name	Description	Version
NX5P3001UK	–40 °C to +85 °C	WLCSP12	wafer level chip-scale package, 12 bumps; body $1.36 \times 1.66 \times 0.51$ mm (Backside Coating included)	NX5P3001

## 5. Marking

Table 2.   Marking codes	
Type number	Marking code
NX5P3001UK	X05P3

## 6. Functional diagram

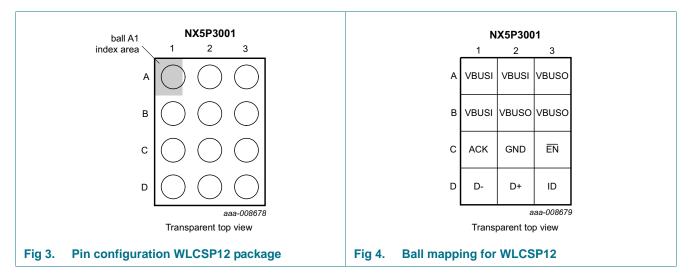




Bidirectional power switch for charger and USB-OTG combinations

## 7. Pinning information

## 7.1 Pinning



## 7.2 Pin description

### Table 3.Pin description

Symbol	Pin	Description
VBUSO	A3, B2, B3	VBUSO (output/input supply)
VBUSI	A1, A2, B1	VBUSI (input supply/output)
ACK	C1	acknowledge condition indicator (open-drain output)
GND	C2	ground (0 V)
EN	C3	enable input (active LOW)
D-	D1	ESD-protection I/O
D+	D2	ESD-protection I/O
ID	D3	ESD-protection I/O

#### 8. **Functional description**

Table	4. Function table <sup>[1]</sup>			
EN	VBUSI	VBUSO	ACK	Operation mode
L	< 3.2 V	< 3.2 V	Z	undervoltage lockout; switch open
L	3.2 V < VBUSI < 6.35 V	< 3.2 V	Z	enabled; switch closed; charging mode
L	< 3.2 V	> 3.2 V	Z	enabled; switch closed; OTG mode
L	Х	Х	0	overtemperature protection; switch open
L	> 6.35 V	Х	0	overvoltage lockout; switch open
Н	Х	Х	Z	disable; switch open

[1] H = HIGH voltage level; L = LOW voltage level, Z = high-impedance OFF-state.

### 8.1 EN-input

A HIGH on EN disables the N-channel MOSFET and all protection circuits putting the device into a low-power mode. A LOW on EN enables the protection circuits and then the N-channel MOSFET.

### 8.2 Undervoltage lockout

When EN is LOW and VBUSI and VBUSO < 3.2 V, the UnderVoltage LockOut (UVLO) circuits disable the N-channel MOSFET. Once VBUSI or VBUSO > 3.3 V and no other protection circuits are active, the state of the N-channel MOSFET is controlled by the EN pin.

### 8.3 Overvoltage lockout

When EN is LOW and VBUSI > 6.35 V, the OverVoltage LockOut (OVLO) circuit disables the N-channel MOSFET and sets the ACK output LOW. Once VBUSI < 6.25 V and no other protection circuits are active, ACK is set high impedance and the state of the N-channel MOSFET is controlled by the EN pin.

### 8.4 Overtemperature protection

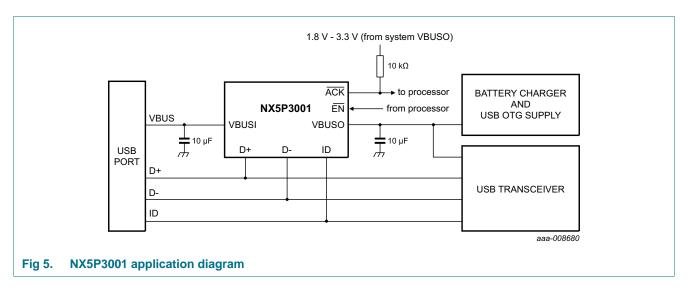
When EN is LOW and the device temperature exceeds 125 °C the overtemperature protection (OTP) circuit disables the N-channel MOSFET and set the ACK output LOW. Once the device temperature decreases to below 115 °C and no other protection circuits are active, ACK is set high impedance and the state of the N-channel MOSFET is controlled by the  $\overline{EN}$  pin.

### 8.5 ACK output

The ACK output is an open-drain output that requires an external pull-up resistor. If OVLO or OTP circuits are activated the ACK output is set LOW to indicate that a fault has occurred. The ACK output will return to high impedance state automatically once the fault condition is removed or EN is HIGH.

## 9. Application diagram

The NX5P3001 typically connects a USB port in a portable, battery operated device. The ACK signal requires an additional external pull-up resistor which should be connected to a supply voltage matching the logic input pin supply level it is connected to.



## **10. Limiting values**

#### Table 5.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
VI	input voltage	VBUSI	<u>[1]</u> –0.5	+32	V
		VBUSO	<u>[1]</u> –0.5	+6.75	V
		EN	[2] -0.5	+6.0	V
		D-, D+, ID	<u>[1]</u> –0.5	+6.0	V
Vo	output voltage	ACK	-0.5	+6.0	V
I <sub>IK</sub>	input clamping current	<u>EN</u> : V <sub>I</sub> < -0.5 V	-50	-	mA
I <sub>SK</sub>	switch clamping current	VBUSI; VBUSO; $V_{I} < -0.5 V$	-50	-	mA
I <sub>SW</sub>	switch current	T <sub>amb</sub> = 85 °C	-	3	А
T <sub>j(max)</sub>	maximum junction temperature		-40	+125	°C
T <sub>stg</sub>	storage temperature		-65	+150	°C

#### Table 5. Limiting values ...continued

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
P <sub>tot</sub>	total power dissipation	$T_{amb} = -40 \ ^{\circ}C \ to \ +85 \ ^{\circ}C$			
		WLCSP12 package	<u>[3]</u>	1.44	W

[1] The minimum and maximum switch voltage ratings may be exceeded if the switch clamping current rating is observed.

[2] The minimum input voltage rating may be exceeded if the input current rating is observed.

[3] For WLCSP12 package: Ptot derates linearly with 13.7 mW/K above 20 °C.

## 11. Recommended operating conditions

Table 6.	Recommended operating conditions							
Symbol	Parameter	Conditions	Min	Max	Unit			
VI	input voltage	VBUSI	3.0	30	V			
		VBUSO	3.0	5.5	V			
		ĒN	0	5.5	V			
V <sub>I/O</sub>	input/output voltage	D-, D+, ID	0	5.5	V			
T <sub>amb</sub>	ambient temperature		-40	+85	°C			

## **12. Thermal characteristics**

#### Table 7. Thermal characteristics

Symbol	Parameter	Conditions	Тур	Unit
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient		<u>[1][2]</u> 73	K/W

[1] The overall Rth(j-a) can vary depending on the board layout. To minimize the effective Rth(j-a), all pins must have a solid connection to larger Cu layer areas e.g. to the power and ground layer. In multi-layer PCB applications, the second layer should be used to create a large heat spreader area right below the device. If this layer is either ground or power, it should be connected with several vias to the top layer connecting to the device ground or supply. Try not to use any solder-stop varnish under the chip.

[2] Please rely on the measurement data given for a rough estimation of the Rth(j-a) in your application. The actual Rth(j-a) value may vary in applications using different layer stacks and layouts

## **13. Static characteristics**

#### Table 8. Static characteristics

 $V_{I(VBUSx)} = 4.0 \text{ V to } 5.5 \text{ VII};$  unless otherwise specified; Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Т	amb = 25	°C	$T_{amb}$ = -40 °	Unit	
			Min	Typ <sup>[2]</sup>	Мах	Min	Мах	
V <sub>IH</sub>	HIGH-level input voltage	EN	1.2	-	-	1.2	-	V
V <sub>IL</sub>	LOW-level input voltage	EN	-	-	0.4	-	0.4	V
V <sub>OL</sub>	LOW-level output voltage	ACK; I <sub>O</sub> = 8 mA	-	-	0.5	-	0.5	V
R <sub>pu</sub>	pull-up resistance	ACK	10	-	200	10	200	kΩ
V <sub>pu</sub>	pull-up voltage	ACK	1.65	-	5.5	1.65	5.5	V

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Symbol	Parameter	Conditions		Т	amb = 25	°C	T <sub>amb</sub> = -40 °	C to +85 °C	Unit
			-	Min	Typ[2]	Max	Min	Мах	
I <sub>GND</sub>	ground current	EN = LOW; I <sub>O</sub> = 0 A; see <u>Figure 6</u> to <u>Figure 11</u>	1	-	280	-	-	400	μΑ
		$\overline{\text{EN}}$ = HIGH; I <sub>O</sub> = 0 A; see <u>Figure 6</u> to <u>Figure 11</u>			8			16	μΑ
I <sub>S(OFF)</sub>	OFF-state leakage current		<u>[3]</u>	-	0.1	-	-	6.5	μΑ
			<u>[4]</u>	-	0.1	-	-	8.5	μΑ
V <sub>UVLO</sub>	undervoltage lockout voltage	VBUSI; VBUSO; $\overline{EN} = LOW$		3.0	3.2	3.4	3.0	3.4	V
V <sub>hys(UVLO)</sub>	undervoltage lockout hysteresis voltage	VBUSI; VBUSO; EN = LOW		-	100	-	-	-	mV
V <sub>OVLO</sub>	overvoltage lockout voltage	VBUSI; $\overline{EN} = LOW$		6.1	6.35	6.8	6.1	6.8	V
V <sub>hys(OVLO)</sub>	overvoltage lockout hysteresis voltage	VBUSI; $\overline{EN} = LOW$		-	100	-	-	-	mV
C <sub>I/O</sub>	input/output capacitance	D-; D+; ID; V <sub>I(VBUSx)</sub> = 5.5 V	<u>[1]</u>	-	3	-	-	-	pF
CI	input capacitance	EN		-	3	-	-	-	pF
C <sub>S(ON)</sub>	ON-state capacitance	VBUSI; VBUSO		-	-	0.5	-	0.5	nF

### Table 8. Static characteristics ...continued

 $V_{I(VBUSx)} = 4.0 \text{ V to 5.5 V}$  unless otherwise specified; Voltages are referenced to GND (ground = 0 V).

[1] VBUSx is the supply voltage associated with the input, either VBUSI or VBUSO.

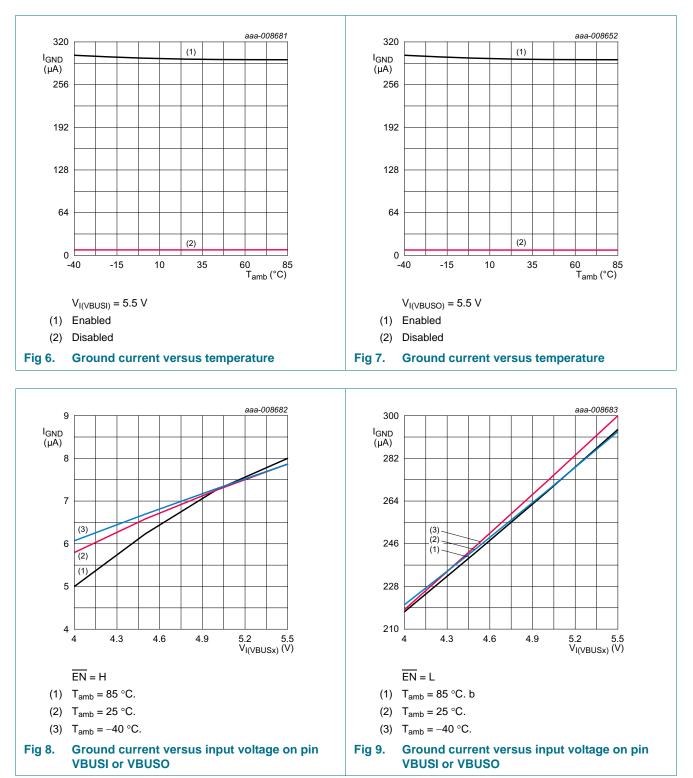
[2] All typical values are measured at  $V_{I(VBUSx)}$  = 5.0 V unless otherwise specified.

[3] Typical value is measured at  $V_{I(VBUSO)} = 0$  V.

[4] Typical value is measured at  $V_{I(VBUSI)} = 0$  V.

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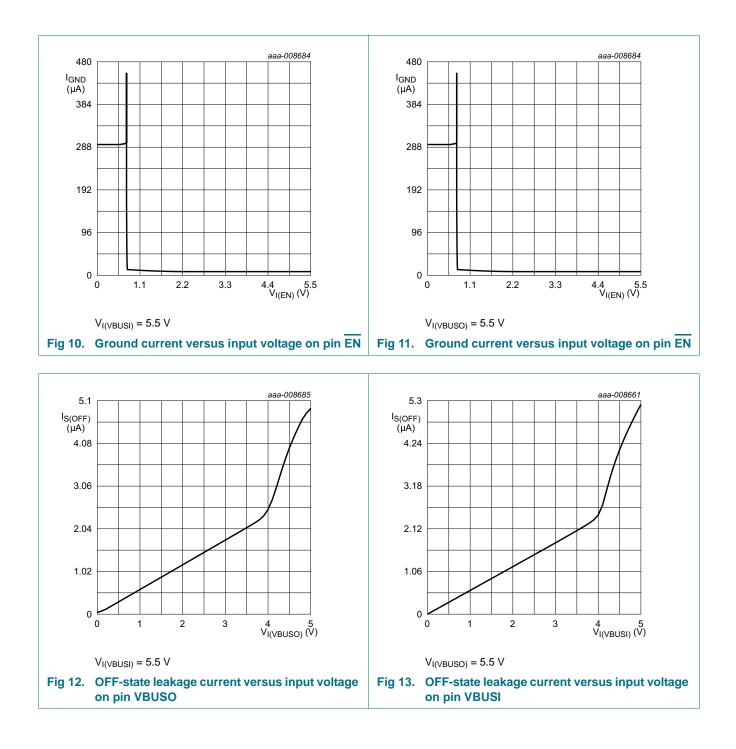
### Bidirectional power switch for charger and USB-OTG combinations



## 13.1 Graphs

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### Bidirectional power switch for charger and USB-OTG combinations



### 13.2 ON resistance

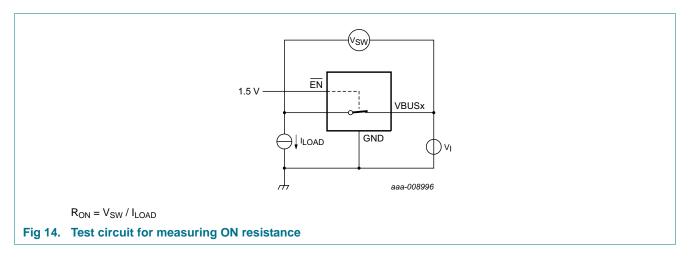
#### Table 9. ON resistance

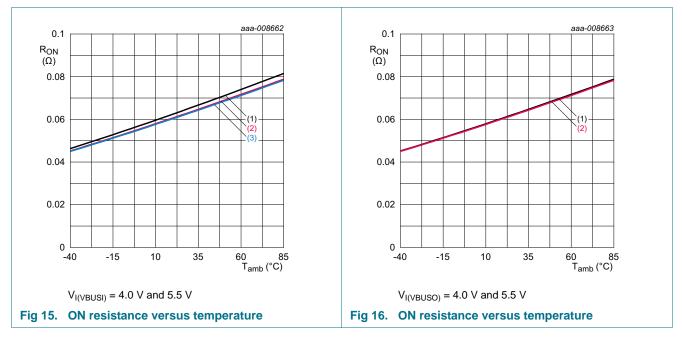
At recommended operating conditions; voltages are referenced to GND (ground = 0 V)

Symbol	Parameter	Conditions			<sub>nb</sub> = 25	°C	$T_{amb}$ = -40	°C to +85 °C	Unit
				Min	Тур	Max	Min	Max	
R <sub>ON</sub>	ON resistance	$V_{I(VBUSx)} = 4.0 V$ to 5.5 V; see <u>Figure 14</u> to <u>Figure 18</u>	<u>[1]</u>						
		$I_{LOAD} = 200 \text{ mA}$		-	62	-	40	100	mΩ
		I <sub>LOAD</sub> = 1.5 A		-	62	-	40	100	mΩ

[1] VBUSx is the supply voltage associated with the input, either VBUSI or VBUSO.

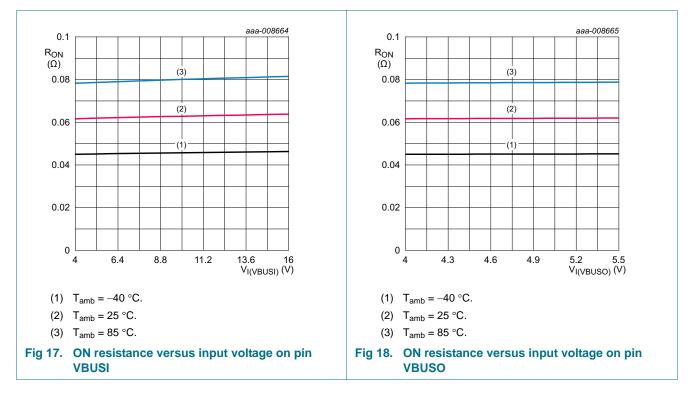
### 13.3 ON resistance test circuit and graphs





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## 14. Dynamic characteristics

### Table 10. Dynamic characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for test circuit see Figure 20.

Symbol	Parameter	Conditions	Ta	<sub>mb</sub> = 25	°C	$T_{amb} = -40 \circ 0$	C to +85 °C	Unit
			Min	Тур	Max	Min	Max	
t <sub>en</sub>	enable time	EN to VBUSO; see Figure 19 and Figure 21 to Figure 24						
		$V_{I(VBUSI)} = 4.0 V$	-	500	-	210	-	μS
		$V_{I(VBUSI)} = 5.5 V$	-	500	-	200	-	μS
		EN to VBUSI; see <u>Figure 19</u> and <u>Figure 21</u> to <u>Figure 24</u>						
		$V_{I(VBUSO)} = 4.0 V$	-	500	-	310	-	μS
		$V_{I(VBUSO)} = 5.5 V$	-	500	-	290	-	μS
t <sub>dis</sub>	disable time	EN to VBUSO; see Figure 19 and Figure 25 to Figure 28						
		$V_{I(VBUSI)} = 4.0 V$	-	1.6	-	-	-	ms
		$V_{I(VBUSI)} = 5.5 V$	-	1.6	-	-	-	ms
		EN to VBUSI; see <u>Figure 19</u> and <u>Figure 25</u> to <u>Figure 28</u>						
		$V_{I(VBUSO)} = 4.0 V$	-	1.6	-	-	-	ms
		$V_{I(VBUSO)} = 5.5 V$	-	1.6	-	-	-	ms

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#### Bidirectional power switch for charger and USB-OTG combinations

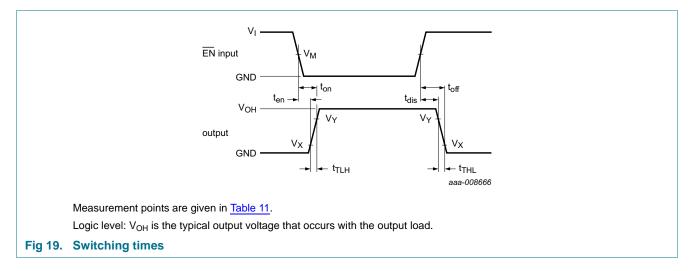
#### Symbol Parameter Conditions T<sub>amb</sub> = 25 °C $T_{amb} = -40 \ ^{\circ}C \ to \ +85 \ ^{\circ}C$ Unit Min Тур Max Min Max EN to VBUSO; see Figure 19 turn-on time ton $V_{I(VBUSI)} = 4.0 V$ 1500 880 -\_ μS $V_{I(VBUSI)} = 5.5 V$ 1600 920 --μS EN to VBUSI; see Figure 19 $V_{I(VBUSO)} = 4.0 V$ 1500 820 \_ -μS $V_{I(VBUSO)} = 5.5 V$ 1700 880 --μS turn-off time EN to VBUSO; see Figure 19 toff $V_{I(VBUSI)} = 4.0 V$ 34.6 -\_ \_ \_ ms $V_{I(VBUSI)} = 5.5 V$ 34.6 ms ---EN to VBUSI; see Figure 19 $V_{I(VBUSO)} = 4.0 V$ 34.6 -\_ ms -- $V_{I(VBUSO)} = 5.5 V$ 34.6 --ms -LOW to HIGH VBUSO; see Figure 19 t<sub>TLH</sub> output $V_{I(VBUSI)} = 4.0 V$ 1000 670 --μS transition time $V_{I(VBUSI)} = 5.5 V$ 1100 720 --μS VBUSI; see Figure 19 $V_{I(VBUSO)} = 4.0 V$ 1000 510 --μS 1200 $V_{I(VBUSO)} = 5.5 V$ -590 -μS VBUSO; see Figure 19 HIGH to LOW t<sub>THL</sub> output $V_{I(VBUSI)} = 4.0 V$ -33.0 \_ -ms transition time $V_{I(VBUSI)} = 5.5 V$ 33.0 --ms -VBUSI; see Figure 19 $V_{I(VBUSO)} = 4.0 V$ 33.0 ms -\_ -- $V_{I(VBUSO)} = 5.5 V$ 33.0 ms \_ -\_ -

#### Table 10. Dynamic characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for test circuit see Figure 20.

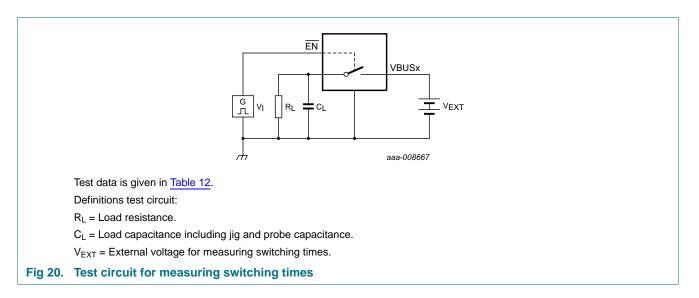
Bidirectional power switch for charger and USB-OTG combinations

## 14.1 Waveforms and test circuit



### Table 11. Measurement points

Supply voltage	EN Input	Output	
VBUSx	V <sub>M</sub>	V <sub>X</sub>	V <sub>Y</sub>
4.0 V to 5.5 V	$0.5  imes V_{I(EN)}$	$0.1 \times V_{OH}$	$0.9  imes V_{OH}$

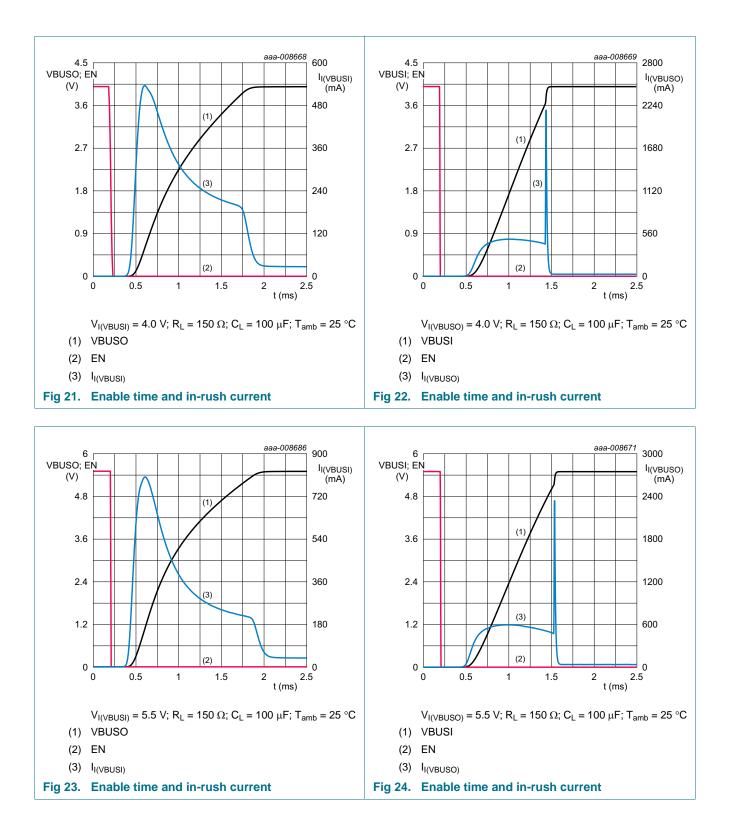


### Table 12. Test data

Supply voltage	Input	Load	
V <sub>EXT</sub>	VI	CL	RL
4.0 V to 5.5 V	1.5 V	100 μF	150 Ω

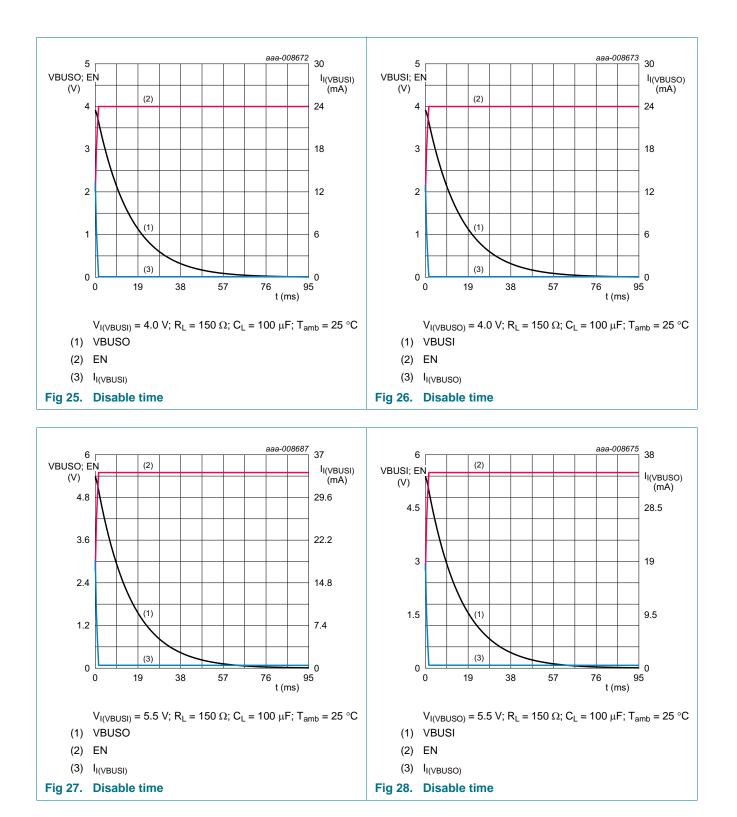
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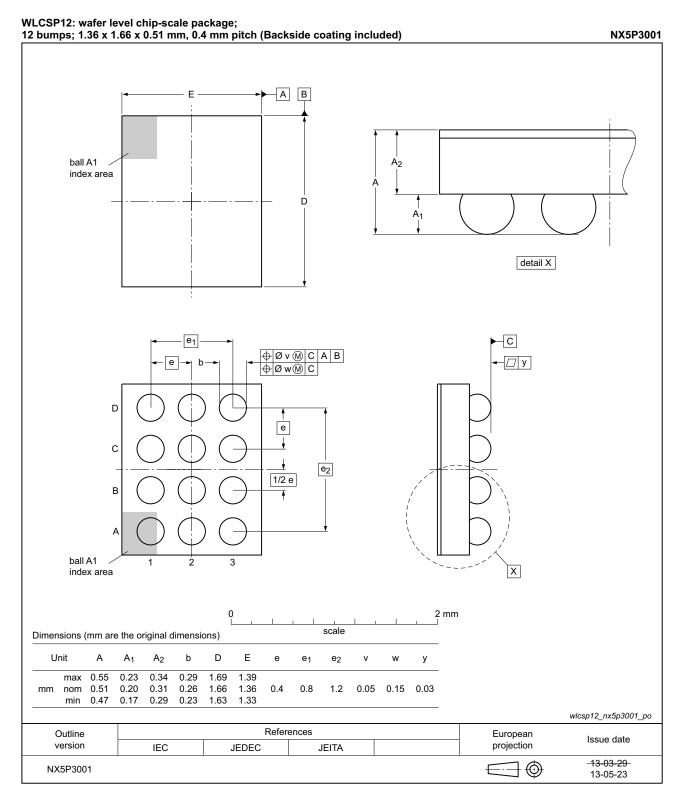


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## 15. Package outline



#### Fig 29. Package outline WLCSP12 package

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## 16. Abbreviations

Table 13. Abbreviations			
Acronym	Description		
CDM	Charged Device Model		
DUT	Device Under Test		
ESD	ElectroStatic Discharge		
HBM	Human Body Model		
MOSFET	Metal-Oxide Semiconductor Field Effect Transistor		
OTP	OverTemperature Protection		
USB-OTG	Universal Serial Bus On-The-Go		
UVLO	UnderVoltage LockOut		
OVLO	OverVoltage LockOut		

## 17. Revision history

### Table 14.Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
NX5P3001 v.1	20130911	Product data sheet	-	-

## **18. Legal information**

### 18.1 Data sheet status

Document status[1][2]	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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Product [short] data sheet	Production	This document contains the product specification.

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[2] The term 'short data sheet' is explained in section "Definitions".

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## NX5P3001

Bidirectional power switch for charger and USB-OTG combinations

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